

# INTERNATIONAL STANDARD

# IEC 61788-7

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## Superconductivity –

### Part 7: Electronic characteristic measurements – Surface resistance of superconductors at microwave frequencies

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International Electrotechnical Commission, 3, rue de Varembé, PO Box 131, CH-1211 Geneva 20, Switzerland  
Telephone: +41 22 919 02 11 Telefax: +41 22 919 03 00 E-mail: [inmail@iec.ch](mailto:inmail@iec.ch) Web: [www.iec.ch](http://www.iec.ch)



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## CONTENTS

FOREWORD.....	4
INTRODUCTION.....	6
1 Scope.....	7
2 Normative references .....	7
3 Terms and definitions .....	7
4 Requirements .....	7
5 Apparatus.....	8
5.1 Measurement system .....	8
5.2 Measurement apparatus for $R_S$ .....	9
5.3 Dielectric rods .....	11
6 Measurement procedure.....	12
6.1 Specimen preparation .....	12
6.2 Set-up .....	12
6.3 Measurement of reference level .....	12
6.4 Measurement of the frequency response of resonators.....	13
6.5 Determination of surface resistance of the superconductor and $\epsilon'$ and $\tan \delta$ of the standard sapphire rods .....	15
7 Precision and accuracy of the test method.....	16
7.1 Surface resistance .....	16
7.2 Temperature.....	17
7.3 Specimen and holder support structure .....	17
7.4 Specimen protection.....	18
8 Test report.....	18
8.1 Identification of test specimen .....	18
8.2 Report of $R_S$ values .....	18
8.3 Report of test conditions.....	18
Annex A (informative) Additional information relating to Clauses 1 to 8.....	19
Bibliography.....	32
Figure 1 – Schematic diagram of measurement system for temperature dependence of $R_S$ using a cryocooler .....	8
Figure 2 – Typical measurement apparatus for $R_S$ .....	10
Figure 3 – Insertion attenuation $IA$ , resonant frequency $f_0$ and half power bandwidth $\Delta f$ , measured at T Kelvin .....	13
Figure 4 – Reflection scattering parameters ( $S_{11}$ and $S_{22}$ ).....	15
Figure 5 – Term definitions in Table 4.....	17
Figure A.1 – Schematic configuration of several measurement methods for the surface resistance .....	20
Figure A.2 – Configuration of a cylindrical dielectric rod resonator short-circuited at both ends by two parallel superconductor films deposited on dielectric substrates .....	22
Figure A.3 – Computed results of the $u$ - $v$ and $W$ - $v$ relations for $TE_{01p}$ mode.....	23
Figure A.4 – Configuration of standard dielectric rods for measurement of $R_S$ and $\tan \delta$ .....	24

Figure A.5 – Three types of dielectric resonators .....	24
Figure A.6 – Mode chart to design $TE_{011}$ resonator short-circuited at both ends by parallel superconductor films [11] .....	27
Figure A.7 – Mode chart to design $TE_{013}$ resonator short-circuited at both ends by parallel superconductor films [11] .....	28
Figure A.8 – Mode chart for $TE_{011}$ closed-type resonator.....	29
Figure A.9 – Mode chart for $TE_{013}$ closed-type resonator.....	30
Table 1 – Typical dimensions of pairs of standard sapphire rods for 12 GHz, 18 GHz and 22 GHz .....	11
Table 2 – Dimensions of superconductor film for 12 GHz, 18 GHz, and 22 GHz.....	12
Table 3 – Specifications on vector network analyzer .....	16
Table 4 – Specifications on sapphire rods.....	16

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## SUPERCONDUCTIVITY –

**Part 7: Electronic characteristic measurements –  
Surface resistance of superconductors  
at microwave frequencies**

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International Standard IEC 61788-7 has been prepared by IEC technical committee 90: Superconductivity.

This second edition cancels and replaces the first edition, published in 2002, of which it constitutes a technical revision. Examples of technical changes made are: 1) closed type resonators are recommended from the viewpoint of the stable measurements, 2) uniaxial-anisotropic characteristics of sapphire rods are taken into consideration for designing the size of the sapphire rods, and 3) recommended measurement frequency of 18 GHz and 22 GHz are added to 12 GHz described in the first edition.

The text of this standard is based on the following documents:

FDIS	Report on voting
90/193/FDIS	90/198/RVD

Full information on the voting for the approval of this standard can be found in the report on voting indicated in the above table.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

IEC 61788 consists of the following parts, under the general title *Superconductivity*:

- Part 1: Critical current measurement – DC critical current of Cu/Nb-Ti composite superconductors
- Part 2: Critical current measurement – DC critical current of Nb<sub>3</sub>Sn composite superconductors
- Part 3: Critical current measurement – DC critical current of Ag- and/or Ag alloy-sheathed Bi-2212 and Bi-2223 oxide superconductors
- Part 4: Residual resistance ratio measurement – Residual resistance ratio of Nb-Ti composite superconductors
- Part 5: Matrix to superconductor volume ratio measurement – Copper to superconductor volume ratio of Cu/Nb-Ti composite superconductors
- Part 6: Mechanical properties measurement – Room temperature tensile test of Cu/Nb-Ti composite superconductors
- Part 7: Electronic characteristic measurements – Surface resistance of superconductors at microwave frequencies
- Part 8: AC loss measurements – Total AC loss measurement of Cu/Nb-Ti composite superconducting wires exposed to a transverse alternating magnetic field by a pickup coil method
- Part 9: Measurements for bulk high temperature superconductors – Trapped flux density of large grain oxide superconductors
- Part 10: Critical temperature measurement – Critical temperature of Nb-Ti, Nb<sub>3</sub>Sn, and Bi-system oxide composite superconductors by a resistance method
- Part 11: Residual resistance ratio measurement – Residual resistance ratio of Nb<sub>3</sub>Sn composite superconductors
- Part 12: Matrix to superconductor volume ratio measurement – Copper to non-copper volume ratio of Nb<sub>3</sub>Sn composite superconducting wires
- Part 13: AC loss measurements – Magnetometer methods for hysteresis loss in Cu/Nb-Ti multifilamentary composites

The committee has decided that the contents of this publication will remain unchanged until the maintenance result date indicated on the IEC web site under "<http://webstore.iec.ch>" in the data related to the specific publication. At this date, the publication will be

- reconfirmed;
- withdrawn;
- replaced by a revised edition, or
- amended.

A bilingual version of this publication may be issued at a later date.

## INTRODUCTION

Since the discovery of some Perovskite-type Cu-containing oxides, extensive research and development (R & D) work on high-temperature oxide superconductors has been, and is being, made worldwide, and its application to high-field magnet machines, low-loss power transmission, electronics and many other technologies is in progress.

In various fields of electronics, especially in telecommunication fields, microwave passive devices such as filters using oxide superconductors are being developed and are undergoing on-site testing [1,2]<sup>1)</sup>.

Superconductor materials for microwave resonators, filters, antenna and delay lines have the advantage of very low loss characteristics. Knowledge of this parameter is of primary importance for the development of new materials on the supplier side and for the design of superconductor microwave components on the customer side. The parameters of superconductor materials needed for the design of microwave low loss components are the surface resistance  $R_s$  and the temperature dependence of the surface resistance.

Recent advances in high  $T_c$  superconductor (HTS) thin films with  $R_s$  several orders of magnitude lower than that of normal metals have increased the need for a reliable characterization technique to measure this property [3,4]. Traditionally, the  $R_s$  of Nb or any other low temperature superconducting material was measured by first fabricating an entire three dimensional resonant cavity and then measuring its  $Q$ -value. The  $R_s$  could be calculated by solving the EM field distribution inside the cavity. Another technique involves placing a small sample inside a larger cavity. This technique has many forms but usually involves the uncertainty introduced by extracting the loss contribution due to the HTS films from the experimentally measured total loss of the cavity.

The best HTS samples are epitaxial films grown on flat crystalline substrates and no high quality films have been grown on any curved surface so far. What is needed is a technique that: can use these small flat samples; requires no sample preparation; does not damage or change the film; is highly repeatable; has great sensitivity (down to 1/1 000<sup>th</sup> the  $R_s$  of copper); has great dynamic range (up to the  $R_s$  of copper); can reach high internal powers with only modest input powers; and has broad temperature coverage (4,2 K to 150 K).

The dielectric resonator method is selected among several methods [5,6,7] to determine the surface resistance at microwave frequencies because it is considered to be the most popular and practical at present. Especially, the sapphire resonator is an excellent tool for measuring the  $R_s$  of HTS materials [8,9].

The test method given in this standard can be also applied to other superconductor bulk plates including low  $T_c$  material.

This standard is intended to provide an appropriate and agreeable technical base for the time being to engineers working in the fields of electronics and superconductivity technology.

The test method covered in this standard is based on the VAMAS (Versailles Project on Advanced Materials and Standards) pre-standardization work on the thin film properties of superconductors.

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1) Figures in square brackets refer to the Bibliography.

## SUPERCONDUCTIVITY –

### Part 7: Electronic characteristic measurements – Surface resistance of superconductors at microwave frequencies

#### 1 Scope

This part of IEC 61788 describes measurement of the surface resistance of superconductors at microwave frequencies by the standard two-resonator method. The object of measurement is the temperature dependence of  $R_s$  at the resonant frequency.

The applicable measurement range of surface resistances for this method is as follows:

- Frequency:  $8 \text{ GHz} < f < 30 \text{ GHz}$
- Measurement resolution:  $0,01 \text{ m}\Omega$  at 10 GHz

The surface resistance data at the measured frequency, and that scaled to 10 GHz, assuming the  $f^2$  rule for comparison, are reported.

#### 2 Normative references

The following referenced documents are indispensable for the application of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 60050-815, *International Electrotechnical Vocabulary (IEV) – Part 815: Superconductivity*